
	<p>SI2372DS-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI2372DS-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CHAN 30V SOT23</p> <p>Datenblätter:  SI2372DS-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 60818 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI2372DS-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CHAN 30V SOT23
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	60818 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	960mW (Ta), 1.7W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	4A (Ta), 5.3A (Tc)
Rds On (Max) @ Id, Vgs	33 mOhm @ 3A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8.9nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	288pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)


SI2372DS-T1-GE3 ist neu im Original, Suche SI2372DS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2372DS-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2372DS-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 SI2372DS AOS SI2372DS AOS	 SI2371EDS-T1-E3 Son SI2371EDS-T1-E3 Son	 SI2374DS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CHAN 20V SOT23	 SI2374DS-T1-E3 VISHAY VISHAY SOT23
 SI2371EDS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 4.8A SOT-23	 SI2371EDS-T1-GE3 Vishay / Siliconix MOSFET P-CH 30V 4.8A SOT-23	 SI2372DS-T1-E3 VISHAY SI2372DS-T1-E3 VISHAY	 SI2374DS-T1-GE3 Vishay / Siliconix MOSFET N-CHAN 20V SOT23

heiße Teile

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|  SI2344DS-E3 |  SI2347DS-T1-GE3 |  SI2347DS-T1-GE3 |  SI2351DS-T1-E3 |  SI2351DS-T1-E3 |
|  SI2351DS-T1-GE3 |  SI2351DS-T1-GE3 |  SI2356DS-T1-GE3 |  SI2356DS-T1-GE3 |  SI2365EDS |
|  SI2365EDS-T1-GE3 |  SI2365EDS-T1-GE3 |  SI2366DS-T1-E3 |  SI2366DS-T1-GE |  SI2366DS-T1-GE3 |
|  SI2366DS-T1-GE3 |  SI2367DS-T1-E3 |  SI2367DS-T1-GE3 |  SI2367DS-T1-GE3 |  SI2369DS-T1-GE3 |
|  SI2369DS-T1-GE3 |  SI2371EDS-T1-GE3 |  SI2371EDS-T1-GE3 |  SI2372DS-T1-E3 |  SI2372DS-T1-GE3 |
|  SI2374DS-T1-GE3 |  SI2374DS-T1-GE3 |  SI2377DS-T1-GE3 |  SI2377EDS |  SI2377EDS-T1-E3 |
|  SI2377EDS-T1-GE3 |  SI2377EDS-T1-GE3 |  SI2392ADS-T1-E3 |  SI2392ADS-T1-GE3 |  SI2392ADS-T1-GE3 |
|  SI2392DS-T1-GE3 |  SI2392DS-T1-GE3 |  SI2399CDS-T1-GE3 |  SI2399DS-T1-GE3 |  SI2399DS-T1-GE3 |
|  SI2400-BS |  SI2400-FS |  SI2400-FSR |  SI2400-KS |  SI2400-KSR |
|  SI2401-FS |  SI2401-FSR |  SI2401-FSR. |  SI2401-KS |  SI2403-FTR |

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